



Welcome to [E-XFL.COM](https://www.e-xfl.com)

Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	384
Number of Logic Elements/Cells	1728
Total RAM Bits	65536
Number of I/O	94
Number of Gates	71693
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	144-TFBGA, CSPBGA
Supplier Device Package	144-LCSBGA (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv50e-7cs144c

Table 9 lists the total number of bits required to configure each device.

Table 9: Virtex-E Bitstream Lengths

Device	# of Configuration Bits
XCV50E	630,048
XCV100E	863,840
XCV200E	1,442,016
XCV300E	1,875,648
XCV400E	2,693,440
XCV600E	3,961,632
XCV1000E	6,587,520
XCV1600E	8,308,992
XCV2000E	10,159,648
XCV2600E	12,922,336
XCV3200E	16,283,712

Slave-Serial Mode

In slave-serial mode, the FPGA receives configuration data in bit-serial form from a serial PROM or other source of serial configuration data. The serial bitstream must be set up at the DIN input pin a short time before each rising edge of an externally generated CCLK.

Table 10: Master/Slave Serial Mode Programming Switching

	Description	Figure References	Symbol	Values	Units
CCLK	DIN setup/hold, slave mode	1/2	T_{DCC}/T_{CCD}	5.0 / 0.0	ns, min
	DIN setup/hold, master mode	1/2	T_{DSCK}/T_{CKDS}	5.0 / 0.0	ns, min
	DOUT	3	T_{CCO}	12.0	ns, max
	High time	4	T_{CCH}	5.0	ns, min
	Low time	5	T_{CCL}	5.0	ns, min
	Maximum Frequency		F_{CC}	66	MHz, max
	Frequency Tolerance, master mode with respect to nominal			+45% –30%	

For more detailed information on serial PROMs, see the PROM data sheet at <http://www.xilinx.com/bvdocs/publications/ds026.pdf>.

Multiple FPGAs can be daisy-chained for configuration from a single source. After a particular FPGA has been configured, the data for the next device is routed to the DOUT pin. The maximum capacity for a single LOUT/DOUT write is $2^{20}-1$ (1,048,575) 32-bit words, or 33,554,400 bits. The data on the DOUT pin changes on the rising edge of CCLK.

The change of DOUT on the rising edge of CCLK differs from previous families, but does not cause a problem for mixed configuration chains. This change was made to improve serial configuration rates for Virtex and Virtex-E only chains.

Figure 13 shows a full master/slave system. A Virtex-E device in slave-serial mode should be connected as shown in the right-most device.

Slave-serial mode is selected by applying <111> or <011> to the mode pins (M2, M1, M0). A weak pull-up on the mode pins makes slave serial the default mode if the pins are left unconnected. However, it is recommended to drive the configuration mode pins externally. Figure 14 shows slave-serial mode programming switching characteristics.

Table 10 provides more detail about the characteristics shown in Figure 14. Configuration must be delayed until the INIT pins of all daisy-chained FPGAs are High.

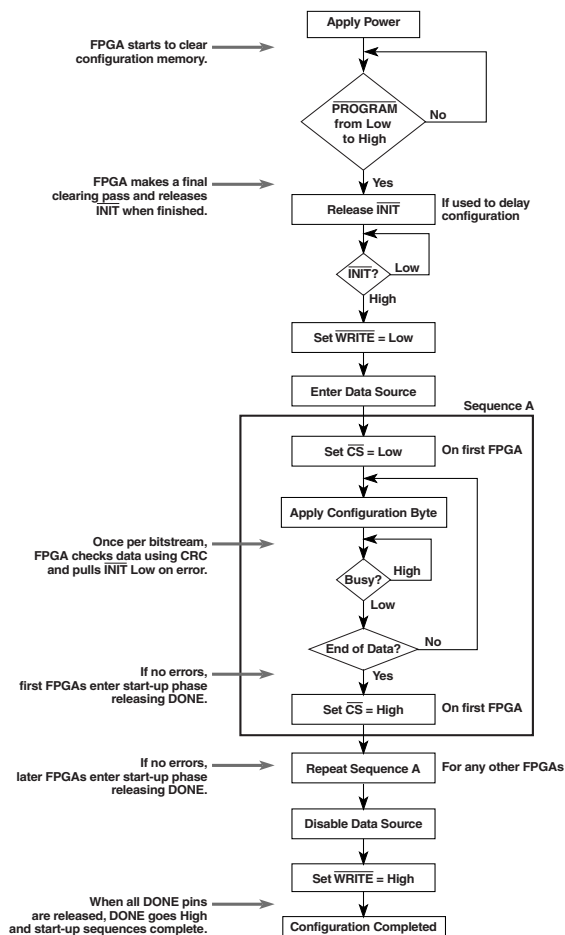


Figure 18: SelectMAP Flowchart for Write Operations

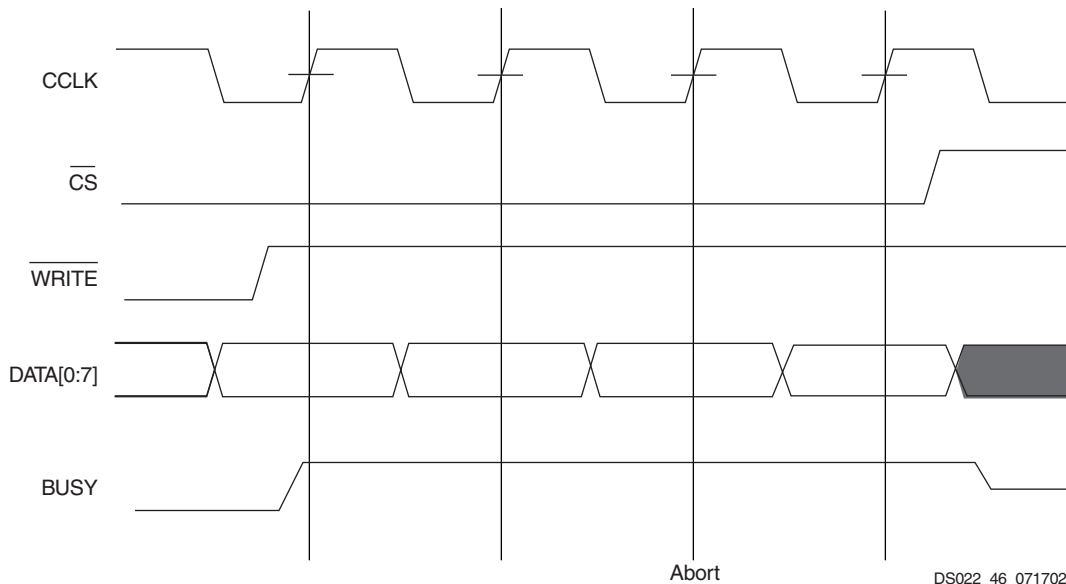


Figure 19: SelectMAP Write Abort Waveforms

Boundary Scan Mode

In the Boundary Scan mode, configuration is done through the IEEE 1149.1 Test Access Port. Note that the

PROGRAM pin must be pulled High prior to reconfiguration. A Low on the PROGRAM pin resets the TAP controller and no JTAG operations can be performed.

Configuration through the TAP uses the CFG_IN instruction. This instruction allows data input on TDI to be converted into data packets for the internal configuration bus.

The following steps are required to configure the FPGA through the Boundary Scan port (when using TCK as a start-up clock).

1. Load the CFG_IN instruction into the Boundary Scan instruction register (IR).
2. Enter the Shift-DR (SDR) state.
3. Shift a configuration bitstream into TDI.
4. Return to Run-Test-Idle (RTI).
5. Load the JSTART instruction into IR.
6. Enter the SDR state.
7. Clock TCK through the startup sequence.
8. Return to RTI.

Configuration and readback via the TAP is always available. The Boundary Scan mode is selected by a <101> or <001> on the mode pins (M2, M1, M0). For details on TAP characteristics, refer to XAPP139.

Configuration Sequence

The configuration of Virtex-E devices is a three-phase process. First, the configuration memory is cleared. Next, configuration data is loaded into the memory, and finally, the logic is activated by a start-up process.

Configuration is automatically initiated on power-up unless it is delayed by the user, as described below. The configuration process can also be initiated by asserting $\overline{\text{PROGRAM}}$. The end of the memory-clearing phase is signalled by $\overline{\text{INIT}}$ going High, and the completion of the entire process is signalled by DONE going High.

The power-up timing of configuration signals is shown in Figure 20.

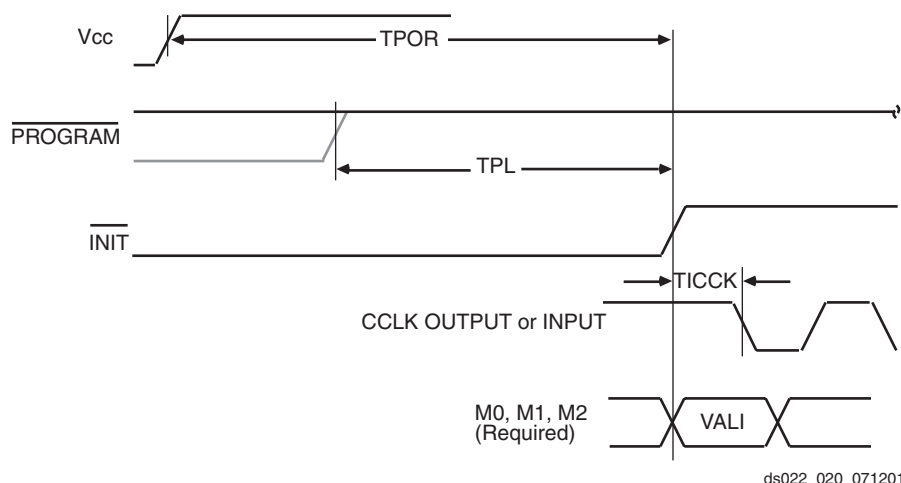


Figure 20: Power-Up Timing Configuration Signals

The corresponding timing characteristics are listed in Table 12.

Table 12: Power-up Timing Characteristics

Description	Symbol	Value	Units
Power-on Reset ¹	T_{POR}	2.0	ms, max
Program Latency	T_{PL}	100.0	μs , max
CCLK (output) Delay	T_{ICCK}	0.5	μs , min
		4.0	μs , max
Program Pulse Width	T_{PROGRAM}	300	ns, min

Notes:

1. T_{POR} delay is the initialization time required after V_{CCINT} and V_{CCO} in Bank 2 reach the recommended operating voltage.

Delaying Configuration

$\overline{\text{INIT}}$ can be held Low using an open-drain driver. An open-drain is required since $\overline{\text{INIT}}$ is a bidirectional open-drain pin that is held Low by the FPGA while the configuration memory is being cleared. Extending the time that the pin is Low causes the configuration sequencer to wait. Thus, configuration is delayed by preventing entry into the phase where data is loaded.

Start-Up Sequence

The default Start-up sequence is that one CCLK cycle after DONE goes High, the global 3-state signal (GTS) is released. This permits device outputs to turn on as necessary.

One CCLK cycle later, the Global Set/Reset (GSR) and Global Write Enable (GWE) signals are released. This permits

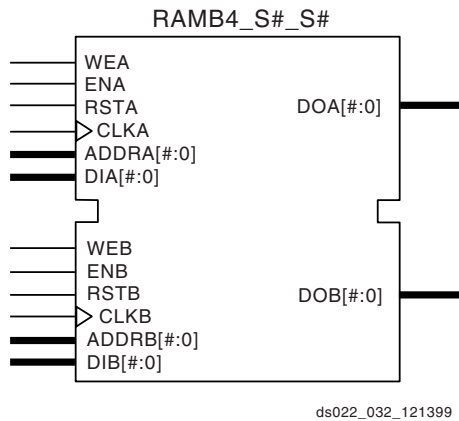


Figure 31: Dual-Port Block SelectRAM+ Memory

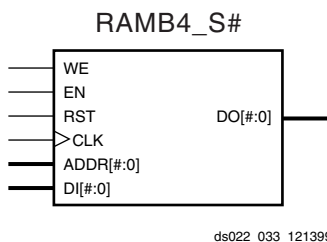


Figure 32: Single-Port Block SelectRAM+ Memory

Table 14: Available Library Primitives

Primitive	Port A Width	Port B Width
RAMB4_S1	1	N/A
RAMB4_S1_S1		1
RAMB4_S1_S2		2
RAMB4_S1_S4		4
RAMB4_S1_S8		8
RAMB4_S1_S16		16
RAMB4_S2	2	N/A
RAMB4_S2_S2		2
RAMB4_S2_S4		4
RAMB4_S2_S8		8
RAMB4_S2_S16		16
RAMB4_S4	4	N/A
RAMB4_S4_S4		4
RAMB4_S4_S8		8
RAMB4_S4_S16		16
RAMB4_S8	8	N/A
RAMB4_S8_S8		8
RAMB4_S8_S16		16
RAMB4_S16	16	N/A
RAMB4_S16_S16		16

Port Signals

Each block SelectRAM+ port operates independently of the others while accessing the same set of 4096 memory cells.

Table 15 describes the depth and width aspect ratios for the block SelectRAM+ memory.

Table 15: Block SelectRAM+ Port Aspect Ratios

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

Clock—CLK[A/B]

Each port is fully synchronous with independent clock pins. All port input pins have setup time referenced to the port CLK pin. The data output bus has a clock-to-out time referenced to the CLK pin.

Enable—EN[A/B]

The enable pin affects the read, write and reset functionality of the port. Ports with an inactive enable pin keep the output pins in the previous state and do not write data to the memory cells.

Write Enable—WE[A/B]

Activating the write enable pin allows the port to write to the memory cells. When active, the contents of the data input bus are written to the RAM at the address pointed to by the address bus, and the new data also reflects on the data out bus. When inactive, a read operation occurs and the contents of the memory cells referenced by the address bus reflect on the data out bus.

Reset—RST[A/B]

The reset pin forces the data output bus latches to zero synchronously. This does not affect the memory cells of the RAM and does not disturb a write operation on the other port.

Address Bus—ADDR[A/B]<#:0>

The address bus selects the memory cells for read or write. The width of the port determines the required width of this bus as shown in Table 15.

Data In Bus—DI[A/B]<#:0>

The data in bus provides the new data value to be written into the RAM. This bus and the port have the same width, as shown in Table 15.

Initialization in Verilog and Synopsys

The block SelectRAM+ structures can be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization. The Synopsys FPGA compiler does not presently support defparam. The initialization values instead attach as attributes to the RAM by a built-in Synopsys dc_script. The translate_off statement stops synthesis translation of the defparam statements. The following code illustrates a module that employs these techniques.

Design Examples

Creating a 32-bit Single-Port RAM

The true dual-read/write port functionality of the block SelectRAM+ memory allows a single port, 128 deep by 32-bit wide RAM to be created using a single block SelectRAM+ cell as shown in **Figure 35**.

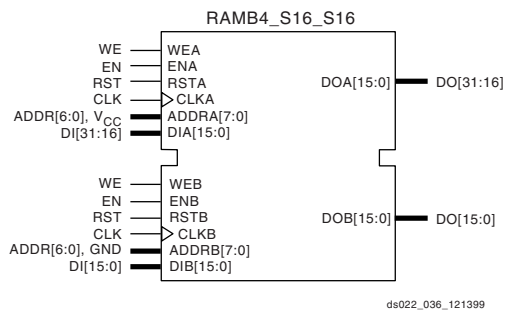


Figure 35: Single Port 128 x 32 RAM

Interleaving the memory space, setting the LSB of the address bus of Port A to 1 (V_{CC}), and the LSB of the

address bus of Port B to 0 (GND), allows a 32-bit wide single port RAM to be created.

Creating Two Single-Port RAMs

The true dual-read/write port functionality of the block SelectRAM+ memory allows a single RAM to be split into two single port memories of 2K bits each as shown in **Figure 36**.

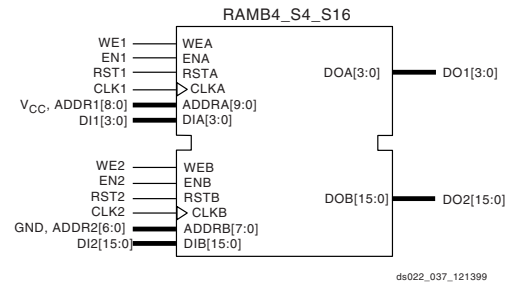


Figure 36: 512 x 4 RAM and 128 x 16 RAM

In this example, a 512K x 4 RAM (Port A) and a 128 x 16 RAM (Port B) are created out of a single block SelectRAM+. The address space for the RAM is split by fixing the MSB of Port A to 1 (V_{CC}) for the upper 2K bits and the MSB of Port B to 0 (GND) for the lower 2K bits.

Block Memory Generation

The CoreGen program generates memory structures using the block SelectRAM+ features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

VHDL Initialization Example

```

library IEEE;
use IEEE.std_logic_1164.all;

entity MYMEM is
port (CLK, WE:in std_logic;
ADDR: in std_logic_vector(8 downto 0);
DIN: in std_logic_vector(7 downto 0);
DOUT: out std_logic_vector(7 downto 0));
end MYMEM;

architecture BEHAVE of MYMEM is
signal logic0, logic1: std_logic;

component RAMB4_S8
--synopsys translate_off
generic( INIT_00,INIT_01, INIT_02, INIT_03, INIT_04, INIT_05, INIT_06, INIT_07,
INIT_08, INIT_09, INIT_0a, INIT_0b, INIT_0c, INIT_0d, INIT_0e, INIT_0f : BIT_VECTOR(255
downto 0)
:= X"0000000000000000000000000000000000000000000000000000000000000000");
--synopsys translate_on
port (WE, EN, RST, CLK: in STD_LOGIC;
ADDR: in STD_LOGIC_VECTOR(8 downto 0);
DI: in STD_LOGIC_VECTOR(7 downto 0);
DO: out STD_LOGIC_VECTOR(7 downto 0));
end component;

--synopsys dc_script_begin
--set_attribute ram0 INIT_00
"0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF" -type string
--set_attribute ram0 INIT_01
"FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210" -type string
--synopsys dc_script_end

begin
logic0 <='0';
logic1 <='1';

ram0: RAMB4_S8
--synopsys translate_off
generic map (
INIT_00 => X"0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF",
INIT_01 => X"FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210")
--synopsys translate_on
port map (WE=>WE, EN=>logic1, RST=>logic0, CLK=>CLK,ADDR=>ADDR, DI=>DIN, DO=>DOUT);
end BEHAVE;

```

LVTTL 3-state output buffers have selectable drive strengths.

The format for LVTTL OBUFT symbol names is as follows:

OBUFT_<slew_rate>_<drive_strength>

where <slew_rate> is either F (Fast) or S (Slow), and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).

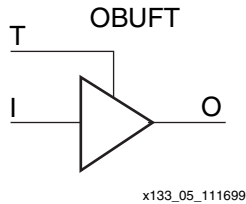


Figure 41: 3-State Output Buffer Symbol (OBUFT)

The following list details variations of the OBUFT symbol.

- OBUFT
- OBUFT_S_2
- OBUFT_S_4
- OBUFT_S_6
- OBUFT_S_8
- OBUFT_S_12
- OBUFT_S_16
- OBUFT_S_24
- OBUFT_F_2
- OBUFT_F_4
- OBUFT_F_6
- OBUFT_F_8
- OBUFT_F_12
- OBUFT_F_16
- OBUFT_F_24
- OBUFT_LVCMOS2
- OBUFT_PCI33_3
- OBUFT_PCI66_3
- OBUFT_GTL
- OBUFT_GTL_P
- OBUFT_HSTL_I
- OBUFT_HSTL_III
- OBUFT_HSTL_IV
- OBUFT_SSTL3_I
- OBUFT_SSTL3_II
- OBUFT_SSTL2_I
- OBUFT_SSTL2_II
- OBUFT_CTT
- OBUFT_AGP
- OBUFT_LVCMOS18
- OBUFT_LVDS
- OBUFT_LVPECL

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS package supports four V_{CCO} banks.

The SelectI/O OBUFT placement restrictions require that within a given V_{CCO} bank each OBUFT share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank.

The LOC property can specify a location for the OBUFT.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak “keeper” circuit. Control this feature by adding the appropriate symbol to the output net of the OBUFT (PULLUP, PULLDOWN, or KEEPER).

The weak “keeper” circuit requires the input buffer within the IOB to sample the I/O signal. So, OBUFTs programmed for an I/O standard that requires a V_{REF} have automatic placement of a V_{REF} in the bank with an OBUFT configured with a weak “keeper” circuit. This restriction does not affect most circuit design as applications using an OBUFT configured with a weak “keeper” typically implement a bidirectional I/O. In this case the IBUF (and the corresponding V_{REF}) are explicitly placed.

The LOC property can specify a location for the OBUFT.

IOBUF

Use the IOBUF symbol for bidirectional signals that require both an input buffer and a 3-state output buffer with an active high 3-state pin. The generic input/output buffer IOBUF appears in Figure 42.

The extension to the base name defines which I/O standard the IOBUF uses. With no extension specified for the generic IOBUF symbol, the assumed standard is LVTTL input buffer and slew rate limited LVTTL with 12 mA drive strength for the output buffer.

The LVTTL IOBUF additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL bidirectional buffers have selectable output drive strengths.

The format for LVTTL IOBUF symbol names is as follows:

IOBUF_<slew_rate>_<drive_strength>

where <slew_rate> is either F (Fast) or S (Slow), and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).

IOB Flip-Flop/Latch Property

The Virtex-E series I/O Block (IOB) includes an optional register on the input path, an optional register on the output path, and an optional register on the 3-state control pin. The design implementation software automatically takes advantage of these registers when the following option for the Map program is specified.

```
map -pr b <filename>
```

Alternatively, the IOB = TRUE property can be placed on a register to force the mapper to place the register in an IOB.

Location Constraints

Specify the location of each SelectI/O symbol with the location constraint LOC attached to the SelectI/O symbol. The external port identifier indicates the value of the location constrain. The format of the port identifier depends on the package chosen for the specific design.

The LOC properties use the following form:

```
LOC=A42
```

```
LOC=P37
```

Output Slew Rate Property

As mentioned above, a variety of symbol names provide the option of choosing the desired slew rate for the output buffers. In the case of the LVTTTL output buffers (OBUF, OBUFT, and IOBUF), slew rate control can be alternatively programmed with the SLEW= property. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals. The SLEW= property has one of the two following values.

```
SLEW=SLOW
```

```
SLEW=FAST
```

Output Drive Strength Property

The desired output drive strength can be additionally specified by choosing the appropriate library symbol. The Xilinx library also provides an alternative method for specifying this feature. For the LVTTTL output buffers (OBUF, OBUFT, and IOBUF), the desired drive strength can be specified with the DRIVE= property. This property could have one of the following seven values.

```
DRIVE=2
```

```
DRIVE=4
```

```
DRIVE=6
```

```
DRIVE=8
```

```
DRIVE=12 (Default)
```

```
DRIVE=16
```

```
DRIVE=24
```

Design Considerations

Reference Voltage (V_{REF}) Pins

Low-voltage I/O standards with a differential amplifier input buffer require an input reference voltage (V_{REF}). Provide the V_{REF} as an external signal to the device.

The voltage reference signal is “banked” within the device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See [Figure 38](#) for a representation of the Virtex-E I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input. After placing a differential amplifier input signal within a given V_{REF} bank, the same external source must drive all I/O pins configured as a V_{REF} input.

Within each V_{REF} bank, any input buffers that require a V_{REF} signal must be of the same type. Output buffers of any type and input buffers can be placed without requiring a reference voltage within the same V_{REF} bank.

Output Drive Source Voltage (V_{CCO}) Pins

Many of the low voltage I/O standards supported by SelectI/O devices require a different output drive source voltage (V_{CCO}). As a result each device can often have to support multiple output drive source voltages.

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS package supports four V_{CCO} banks.

Output buffers within a given V_{CCO} bank must share the same output drive source voltage. Input buffers for LVTTTL, LVCMOS2, LVCMOS18, PCI33_3, and PCI 66_3 use the V_{CCO} voltage for Input V_{CCO} voltage.

Transmission Line Effects

The delay of an electrical signal along a wire is dominated by the rise and fall times when the signal travels a short distance. Transmission line delays vary with inductance and capacitance, but a well-designed board can experience delays of approximately 180 ps per inch.

Transmission line effects, or reflections, typically start at 1.5" for fast (1.5 ns) rise and fall times. Poor (or non-existent) termination or changes in the transmission line impedance cause these reflections and can cause additional delay in longer traces. As system speeds continue to increase, the effect of I/O delays can become a limiting factor and therefore transmission line termination becomes increasingly more important.

Termination Techniques

A variety of termination techniques reduce the impact of transmission line effects.

The following are output termination techniques:

- None
- Series
- Parallel (Shunt)
- Series and Parallel (Series-Shunt)

Table 21: Guidelines for Max Number of Simultaneously Switching Outputs per Power/Ground Pair (Continued)

Standard	Package		
	BGA, CS, FGA	HQ	PQ, TQ
HSTL Class I	18	13	9
HSTL Class III	9	7	5
HSTL Class IV	5	4	3
SSTL2 Class I	15	11	8
SSTL2 Class II	10	7	5
SSTL3 Class I	11	8	6
SSTL3 Class II	7	5	4
CTT	14	10	7
AGP	9	7	5

Note: This analysis assumes a 35 pF load for each output.

Table 22: Virtex-E Equivalent Power/Ground Pairs

Pkg/Part	XCV100E	XCV200E	XCV300E	XCV400E	XCV600E	XCV1000E	XCV1600E	XCV2000E
CS144	12	12						
PQ240	20	20	20	20				
HQ240					20	20		
BG352	20	32	32					
BG432			32	40	40			
BG560				40	40	56	58	60
FG256 ⁽¹⁾	20	24	24					
FG456		40	40					
FG676				54	56			
FG680 ⁽²⁾					46	56	56	56
FG860						58	60	64
FG900					56	58		60
FG1156						96	104	120

Notes:

1. Virtex-E devices in FG256 packages have more V_{CCO} than Virtex series devices.
2. FG680 numbers are preliminary.

The register elements can be packed in the IOB using the IOB property to TRUE on the register or by using the “map-pr [ilolb]” where “i” is inputs only, “o” is outputs only and “b” is both inputs and outputs.

To improve design coding times VHDL and Verilog synthesis macro libraries have been developed to explicitly create these structures. The input library macros are listed below. The 3-state is configured to be 3-stated at GSR and when the PRE,CLR,S or R is asserted and shares its clock enable with the output register. If this is not desirable then the library can be updated by the user for the desired functionality. The O and OB inputs to the macros are the external net connections.

Creating a LVDS Bidirectional Buffer

LVDS bidirectional buffers can be placed in a wide number of IOB locations. The exact locations are dependent on the package used. The Virtex-E package information lists the possible locations as IO_L#P for the P-side and IO_L#N for the N-side, where # is the pair number.

HDL Instantiation

Both bidirectional buffers are required to be instantiated in the design and placed on the correct IO_L#P and IO_L#N locations. The IOB must have the same net source the following pins, clock (C), set/reset (SR), 3-state (T), 3-state clock enable (TCE), output (O), output clock enable (OCE). In addition, the output (O) pins must be inverted with respect to each other, and if output registers are used, the INIT states must be opposite values (one HIGH and one LOW). If 3-state registers are used, they must be initialized to the same state. Failure to follow these rules leads to DRC errors in the software.

VHDL Instantiation

```
data0_p: IOBUF_LVDS port map
(I=>data_out(0), T=>data_tri,
IO=>data_p(0), O=>data_int(0));
data0_inv: INV port map
(I=>data_out(0), O=>data_n_out(0));
data0_n : IOBUF_LVDS port map
(I=>data_n_out(0), T=>data_tri,
IO=>data_n(0), O=>open);
```

Verilog Instantiation

```
IOBUF_LVDS data0_p(.I(data_out[0]),
.T(data_tri), .IO(data_p[0]),
.O(data_int[0]));
INV data0_inv (.I(data_out[0],
.O(data_n_out[0]));
IOBUF_LVDS
data0_n(.I(data_n_out[0]),.T(data_tri),.
IO(data_n[0]).O());
```

Location Constraints

All LVDS buffers must be explicitly placed on a device. For the output buffers this can be done with the following constraint in the .ucf or .ncf file.

```
NET data_p<0> LOC = D28; # IO_L0P
NET data_n<0> LOC = B29; # IO_L0N
```

Synchronous vs. Asynchronous Bidirectional Buffers

If the output side of the bidirectional buffers are synchronous (registered in the IOB), then any IO_L#PIN pair can be used. If the output side of the bidirectional buffers are asynchronous (no output register), then they must use one of the pairs that is a part of the asynchronous LVDS IOB group. This applies for either the 3-state pin or the data out pin.

The LVDS pairs that can be used as asynchronous bidirectional buffers are listed in the Virtex-E pinout tables. Some pairs are marked as asynchronous capable for all devices in that package, and others are marked as available only for that device in the package. If the device size might change at some point in the product's lifetime, then only the common pairs for all packages should be used.

Adding Output and 3-State Registers

All LVDS buffers can have an output and input registers in the IOB. The output registers must be in both the P-side and N-side IOBs, the input register is only in the P-side. All the normal IOB register options are available (FD, FDE, FDC, FDCE, FDP, FDPE, FDR, FDRE, FDS, FDSE, LD, LDE, LDC, LDCE, LDP, LDPE). The register elements can be inferred or explicitly instantiated in the HDL code. Special care must be taken to insure that the D pins of the registers are inverted and that the INIT states of the registers are opposite. The 3-state (T), 3-state clock enable (CE), clock pin (C), output clock enable (CE), and set/reset (CLR/PRE or S/R) pins must connect to the same source. Failure to do this leads to a DRC error in the software.

The register elements can be packed in the IOB using the IOB property to TRUE on the register or by using the “map-pr [ilolb]” where “i” is inputs only, “o” is outputs only and “b” is both inputs and outputs. To improve design coding times VHDL and Verilog synthesis macro libraries have been developed to explicitly create these structures. The bidirectional I/O library macros are listed in Table 44. The 3-state is configured to be 3-stated at GSR and when the PRE,CLR,S or R is asserted and shares its clock enable with the output and input register. If this is not desirable then the library can be updated by the user for the desired functionality. The I/O and IOB inputs to the macros are the external net connections.

Table 2: IOB Input Switching Characteristics (Continued)

			Speed Grade ⁽¹⁾				Units
Description ⁽²⁾	Symbol	Device	Min	-8	-7	-6	
Sequential Delays							
Clock CLK							
Minimum Pulse Width, High	T _{CH}	All	0.56	1.2	1.3	1.4	ns, min
Minimum Pulse Width, Low	T _{CL}		0.56	1.2	1.3	1.4	ns, min
Clock CLK to output IQ	T _{IOCKIQ}		0.18	0.4	0.7	0.7	ns, max
Setup and Hold Times with respect to Clock at IOB Input Register							
Pad, no delay	T _{IOPICK} / T _{IOICKP}	All	0.69 / 0	1.3 / 0	1.4 / 0	1.5 / 0	ns, min
Pad, with delay	T _{IOPICKD} / T _{IOICKPD}	XCV50E	1.25 / 0	2.8 / 0	2.9 / 0	2.9 / 0	ns, min
		XCV100E	1.25 / 0	2.8 / 0	2.9 / 0	2.9 / 0	ns, min
		XCV200E	1.33 / 0	3.0 / 0	3.1 / 0	3.1 / 0	ns, min
		XCV300E	1.33 / 0	3.0 / 0	3.1 / 0	3.1 / 0	ns, min
		XCV400E	1.37 / 0	3.1 / 0	3.2 / 0	3.2 / 0	ns, min
		XCV600E	1.49 / 0	3.4 / 0	3.5 / 0	3.5 / 0	ns, min
		XCV1000E	1.49 / 0	3.4 / 0	3.5 / 0	3.5 / 0	ns, min
		XCV1600E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
		XCV2000E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
		XCV2600E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
XCV3200E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min		
ICE input	T _{IOICECK} / T _{IOCKICE}	All	0.28 / 0.0	0.55 / 0.01	0.7 / 0.01	0.7 / 0.01	ns, min
SR input (IFF, synchronous)	T _{IOSRCKI}	All	0.38	0.8	0.9	1.0	ns, min
Set/Reset Delays							
SR input to IQ (asynchronous)	T _{IOSRIQ}	All	0.54	1.1	1.2	1.4	ns, max
GSR to output IQ	T _{GSRQ}	All	3.88	7.6	8.5	9.7	ns, max

Notes:

1. A Zero "0" Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed "best-case", but if a "0" is listed, there is no positive hold time.
2. Input timing t_i for LVTTTL is measured at 1.4 V. For other I/O standards, see Table 4.

Revision History

The following table shows the revision history for this document.

Date	Version	Revision
12/7/99	1.0	Initial Xilinx release.
1/10/00	1.1	Re-released with spd.txt v. 1.18, FG860/900/1156 package information, and additional DLL, Select RAM and SelectI/O information.
1/28/00	1.2	Added Delay Measurement Methodology table, updated SelectI/O section, Figures 30, 54, & 55, text explaining Table 5, T_{BYP} values, buffered Hex Line info, p. 8, I/O Timing Measurement notes, notes for Tables 15, 16, and corrected F1156 pinout table footnote references.
2/29/00	1.3	Updated pinout tables, V_{CC} page 20, and corrected Figure 20.
5/23/00	1.4	Correction to table on p. 22.
7/10/00	1.5	- Numerous minor edits. - Data sheet upgraded to Preliminary. - Preview -8 numbers added to Virtex-E Electrical Characteristics tables.
8/1/00	1.6	- Reformatted entire document to follow new style guidelines. - Changed speed grade values in tables on pages 35-37.
9/20/00	1.7	- Min values added to Virtex-E Electrical Characteristics tables. - XCV2600E and XCV3200E numbers added to Virtex-E Electrical Characteristics tables (Module 3). - Corrected user I/O count for XCV100E device in Table 1 (Module 1). - Changed several pins to "No Connect in the XCV100E" and removed duplicate V_{CCINT} pins in Table ~ (Module 4). - Changed pin J10 to "No connect in XCV600E" in Table 74 (Module 4). - Changed pin J30 to "VREF option only in the XCV600E" in Table 74 (Module 4). - Corrected pair 18 in Table 75 (Module 4) to be "AO in the XCV1000E, XCV1600E".
11/20/00	1.8	- Upgraded speed grade -8 numbers in Virtex-E Electrical Characteristics tables to Preliminary. - Updated minimums in Table 13 and added notes to Table 14. - Added to note 2 to Absolute Maximum Ratings. - Changed speed grade -8 numbers for $T_{SHCKO32}$, T_{REG}, T_{BCCS}, and T_{ICKOF}. - Changed all minimum hold times to -0.4 under Global Clock Set-Up and Hold for LVTTTL Standard, with DLL. - Revised maximum T_{DLLPW} in -6 speed grade for DLL Timing Parameters. - Changed GCLK0 to BA22 for FG860 package in Table 46.
2/12/01	1.9	- Revised footnote for Table 14. - Added numbers to Virtex-E Electrical Characteristics tables for XCV1000E and XCV2000E devices. - Updated Table 27 and Table 78 to include values for XCV400E and XCV600E devices. - Revised Table 62 to include pinout information for the XCV400E and XCV600E devices in the BG560 package. - Updated footnotes 1 and 2 for Table 76 to include XCV2600E and XCV3200E devices.
4/02/01	2.0	- Updated numerous values in Virtex-E Switching Characteristics tables. - Converted data sheet to modularized format. See the Virtex-E Data Sheet section.
4/19/01	2.1	Updated values in Virtex-E Switching Characteristics tables.

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
4	IO_VREF_4_L53P_Y	AC12
4	IO_L53N_Y	AD12
4	IO_L54P	AE12
4	IO_L54N	AF12
4	IO	AD13 ¹
4	IO_LVDS_DLL_L55P	AC13
4	GCK0	AE13
5	GCK1	AF14
5	IO_LVDS_DLL_L55N	AD14
5	IO	AF15 ¹
5	IO	AE15
5	IO_L56P_Y	AD15
5	IO_VREF_5_L56N_Y	AC15
5	IO_L57P_Y	AE16
5	IO_L57N_Y	AE17
5	IO	AD16 ¹
5	IO_L58P	AC16
5	IO_L58N	AF18
5	IO	AE18 ¹
5	IO_L59P_YY	AD17
5	IO_L59N_YY	AC17
5	IO_L60P_YY	AD18
5	IO_VREF_5_L60N_YY	AC18
5	IO_L61P_Y	AF20
5	IO_L61N_Y	AE20
5	IO	AD19
5	IO	AC19 ¹
5	IO	AF21 ¹
5	IO_L62P_YY	AE21
5	IO_VREF_5_L62N_YY	AD20
5	IO_L63P_YY	AF23
5	IO_L63N_YY	AE22
5	IO	AD21 ¹

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
5	IO_L64P_YY	AC21
5	IO_VREF_5_L64N_YY	AE23 ²
5	IO	AD22
5	IO	AF24 ¹
5	IO	AC22 ¹
6	IO_L65N_YY	AC24
6	IO_L65P_YY	AD25
6	IO	AB24 ¹
6	IO	AA23 ¹
6	IO	AC25
6	IO_VREF_6_L66N_YY	AD26 ²
6	IO_L66P_YY	AC26
6	IO	Y23 ¹
6	IO_L67N_YY	AA24
6	IO_L67P_YY	AB25
6	IO_VREF_6_L68N_Y	AA25
6	IO_L68P_Y	Y24
6	IO	Y25 ¹
6	IO	AA26 ¹
6	IO_L69N	V23
6	IO_L69P	W24
6	IO	W25
6	IO_VREF_6_L70N_Y	Y26
6	IO_L70P_Y	U23
6	IO_L71N_YY	V25
6	IO_L71P_YY	U24
6	IO	V26 ¹
6	IO_L72N	T23
6	IO_L72P	U25
6	IO	T24 ¹
6	IO_L73N_YY	T25
6	IO_L73P_YY	T26
6	IO_VREF_6_L74N_Y	R24

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
48	2	N1	P4	√	D3
49	2	P3	P2	4	-
50	2	R3	R4	1	VREF
51	2	R1	T3	√	-
52	3	U4	U2	1	VREF
53	3	U1	V3	4	-
54	3	V4	V2	√	VREF
55	3	W3	W4	1	-
56	3	Y1	Y3	1	-
57	3	Y4	Y2	4	-
58	3	AA3	AB1	√	D5
59	3	AB3	AB4	√	VREF
60	3	AD1	AC3	1	VREF
61	3	AC4	AD2	4	-
62	3	AD3	AD4	√	VREF
63	3	AF2	AE3	1	-
64	3	AE4	AG1	5	-
65	3	AG2	AF3	1	VREF
66	3	AF4	AH1	4	-
67	3	AH2	AG3	3	-
68	3	AG4	AJ2	√	INIT
69	4	AJ4	AK3	√	-
70	4	AH5	AK4	1	-
71	4	AJ5	AH6	√	-
72	4	AL4	AK5	√	VREF
73	4	AJ6	AH7	2	-
74	4	AL5	AK6	√	-
75	4	AJ7	AL6	√	VREF
76	4	AH9	AJ8	1	-
77	4	AK8	AJ9	1	VREF
78	4	AL8	AK9	√	VREF
79	4	AK10	AL10	√	-

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
80	4	AH12	AK11	√	-
81	4	AJ12	AK12	√	-
82	4	AH13	AJ13	√	-
83	4	AL13	AK14	√	VREF
84	4	AH14	AJ14	1	-
85	4	AK15	AJ15	1	VREF
86	5	AH15	AL17	NA	IO_LVDS_DLL
87	5	AK17	AJ17	1	VREF
88	5	AH17	AK18	1	-
89	5	AL19	AJ18	√	VREF
90	5	AH18	AL20	√	-
91	5	AK20	AH19	√	-
92	5	AJ20	AK21	√	-
93	5	AJ21	AL22	√	-
94	5	AJ22	AK23	√	VREF
95	5	AH22	AL24	1	VREF
96	5	AK24	AH23	1	-
97	5	AK25	AJ25	√	VREF
98	5	AL26	AK26	√	-
99	5	AH25	AL27	2	-
100	5	AJ26	AK27	√	VREF
101	5	AH26	AL28	√	-
102	5	AJ27	AK28	1	-
103	6	AH30	AJ30	√	-
104	6	AH31	AG28	3	-
105	6	AG30	AG29	4	-
106	6	AG31	AF28	1	VREF
107	6	AF30	AF29	5	-
108	6	AF31	AE28	1	-
109	6	AD28	AE30	√	VREF
110	6	AD31	AD30	4	-
111	6	AC29	AC28	1	VREF

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
NA	VCCINT	N29	
NA	VCCINT	N33	
NA	VCCINT	U5	
NA	VCCINT	U30	
NA	VCCINT	Y2	
NA	VCCINT	Y31	
NA	VCCINT	AB2	
NA	VCCINT	AB32	
NA	VCCINT	AD2	
NA	VCCINT	AD32	
NA	VCCINT	AG3	
NA	VCCINT	AG31	
NA	VCCINT	AJ13	
NA	VCCINT	AK8	
NA	VCCINT	AK11	
NA	VCCINT	AK17	
NA	VCCINT	AK20	
NA	VCCINT	AL14	
NA	VCCINT	AL22	
NA	VCCINT	AL27	
NA	VCCINT	AN25	
0	VCCO	A22	
0	VCCO	A26	
0	VCCO	A30	
0	VCCO	B19	
0	VCCO	B32	
1	VCCO	A10	
1	VCCO	A16	
1	VCCO	B13	
1	VCCO	C3	
1	VCCO	E5	
2	VCCO	B2	
2	VCCO	D1	
2	VCCO	H1	

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
2	VCCO	M1	
2	VCCO	R2	
3	VCCO	V1	
3	VCCO	AA2	
3	VCCO	AD1	
3	VCCO	AK1	
3	VCCO	AL2	
4	VCCO	AN4	
4	VCCO	AN8	
4	VCCO	AN12	
4	VCCO	AM2	
4	VCCO	AM15	
5	VCCO	AL31	
5	VCCO	AM21	
5	VCCO	AN18	
5	VCCO	AN24	
5	VCCO	AN30	
6	VCCO	W32	
6	VCCO	AB33	
6	VCCO	AF33	
6	VCCO	AK33	
6	VCCO	AM32	
7	VCCO	C32	
7	VCCO	D33	
7	VCCO	K33	
7	VCCO	N32	
7	VCCO	T33	
NA	GND	A1	
NA	GND	A7	
NA	GND	A12	
NA	GND	A14	
NA	GND	A18	
NA	GND	A20	
NA	GND	A24	

Table 22: FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	GND	D20
NA	GND	D12
NA	GND	C39
NA	GND	C37
NA	GND	C3
NA	GND	C20
NA	GND	C1
NA	GND	B39
NA	GND	B38
NA	GND	B2
NA	GND	B1
NA	GND	AW39
NA	GND	AW38
NA	GND	AW37
NA	GND	AW3
NA	GND	AW2
NA	GND	AW1
NA	GND	AV39
NA	GND	AV38
NA	GND	AV2
NA	GND	AV1
NA	GND	AU39
NA	GND	AU37
NA	GND	AU3
NA	GND	AU20
NA	GND	AU1
NA	GND	AT4
NA	GND	AT36
NA	GND	AT28
NA	GND	AT20
NA	GND	AT12
NA	GND	AR5
NA	GND	AR35
NA	GND	AR28
NA	GND	AR21
NA	GND	AR20

Table 22: FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	GND	AR19
NA	GND	AR12
NA	GND	AH5
NA	GND	AH4
NA	GND	AH36
NA	GND	AH35
NA	GND	AA5
NA	GND	AA35
NA	GND	A39
NA	GND	A38
NA	GND	A37
NA	GND	A3
NA	GND	A2
NA	GND	A1

Notes:

1. V_{REF} or I/O option only in the XCV1000E, 1600E, 2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV1600E, 2000E; otherwise, I/O option only.
3. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.

Table 24: FG860 — XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	VCCO_1	F15
NA	VCCO_1	F19
NA	VCCO_1	F20
NA	VCCO_1	F7
NA	VCCO_1	F8
NA	VCCO_2	G6
NA	VCCO_2	H6
NA	VCCO_2	L6
NA	VCCO_2	M6
NA	VCCO_2	P6
NA	VCCO_2	R6
NA	VCCO_2	W6
NA	VCCO_2	Y6
NA	VCCO_3	AC6
NA	VCCO_3	AD6
NA	VCCO_3	AH6
NA	VCCO_3	AJ6
NA	VCCO_3	AL6
NA	VCCO_3	AM6
NA	VCCO_3	AR6
NA	VCCO_3	AT6
NA	VCCO_4	AU11
NA	VCCO_4	AU12
NA	VCCO_4	AU14
NA	VCCO_4	AU15
NA	VCCO_4	AU19
NA	VCCO_4	AU20
NA	VCCO_4	AU7
NA	VCCO_4	AU8
NA	VCCO_5	AU23
NA	VCCO_5	AU24
NA	VCCO_5	AU28
NA	VCCO_5	AU29
NA	VCCO_5	AU31
NA	VCCO_5	AU32
NA	VCCO_5	AU35
NA	VCCO_5	AU36

Table 24: FG860 — XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	VCCO_6	AC37
NA	VCCO_6	AD37
NA	VCCO_6	AH37
NA	VCCO_6	AJ37
NA	VCCO_6	AL37
NA	VCCO_6	AM37
NA	VCCO_6	AR37
NA	VCCO_6	AT37
NA	VCCO_7	G37
NA	VCCO_7	H37
NA	VCCO_7	L37
NA	VCCO_7	M37
NA	VCCO_7	P37
NA	VCCO_7	R37
NA	VCCO_7	W37
NA	VCCO_7	Y37
NA	GND	N6
NA	GND	N5
NA	GND	N38
NA	GND	N37
NA	GND	F6
NA	GND	F37
NA	GND	F30
NA	GND	F22
NA	GND	F21
NA	GND	F13
NA	GND	E5
NA	GND	E38
NA	GND	E30
NA	GND	E22
NA	GND	E21
NA	GND	E13
NA	GND	D42
NA	GND	D4
NA	GND	D39
NA	GND	D1

Table 25: FG860 Differential Pin Pair Summary
XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
52	1	D11	B15	√	VREF
53	1	C14	E11	2	-
54	1	B14	C10	2	-
55	1	E10	A13	√	VREF
56	1	C9	C13	√	-
57	1	A12	D9	1	VREF
58	1	C12	E9	1	-
59	1	D8	B12	√	VREF
60	1	E8	A11	√	-
61	1	A10	C7	5	-
62	1	B10	C6	5	-
63	1	B9	A9	√	VREF
64	1	E7	A8	√	-
65	1	C5	B8	5	-
66	1	A6	A7	1	VREF
67	1	D6	B7	1	-
68	1	C4	A5	2	-
69	1	E6	B6	√	CS
70	2	F5	D2	√	DIN, D0
71	2	E4	E2	3	-
72	2	D3	F2	1	-
73	2	E1	F4	2	VREF
74	2	G2	E3	4	-
75	2	F1	G5	2	-
76	2	G1	F3	1	VREF
77	2	G4	H1	√	-
78	2	J2	G3	2	-
79	2	H5	K2	1	-
80	2	H4	K1	√	VREF
81	2	L2	L3	√	-
82	2	L1	J5	5	VREF
83	2	J4	M3	2	-
84	2	J3	M1	√	VREF
85	2	N2	K4	√	-

Table 25: FG860 Differential Pin Pair Summary
XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
86	2	N3	K3	2	-
87	2	L5	P2	√	D1
88	2	P3	L4	√	D2
89	2	P1	R2	3	-
90	2	M5	R3	1	-
91	2	M4	R1	2	-
92	2	N4	T2	4	-
93	2	P5	T3	2	-
94	2	P4	T1	1	VREF
95	2	U2	R4	√	-
96	2	U3	T5	2	-
97	2	T4	V2	1	-
98	2	U5	V3	√	D3
99	2	V1	V5	√	-
100	2	W2	V4	5	-
101	2	W5	W1	2	-
102	2	Y2	W4	√	VREF
103	2	Y1	Y5	√	-
104	2	AA1	Y4	2	VREF
105	2	AA4	AA2	√	-
106	3	AB3	AC4	2	VREF
107	3	AB1	AC5	√	-
108	3	AD4	AC3	√	VREF
109	3	AC1	AD5	2	-
110	3	AE4	AD3	5	-
111	3	AE5	AD2	√	-
112	3	AE1	AF5	√	VREF
113	3	AE2	AG4	1	-
114	3	AG5	AF1	2	-
115	3	AH4	AF2	√	-
116	3	AF3	AJ4	1	VREF
117	3	AG1	AJ5	2	-
118	3	AG2	AK4	4	-
119	3	AG3	AL4	2	-

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
1	IO	J20 ⁵
1	IO	L18 ⁴
1	IO_LVDS_DLL_L34P	E16
1	IO_L35N_YY	B16
1	IO_VREF_L35P_YY	F16 ²
1	IO_L36N_YY	A16
1	IO_L36P_YY	H16
1	IO_L37N_YY	C16
1	IO_VREF_L37P_YY	K15
1	IO_L38N_YY	K16
1	IO_L38P_YY	G16
1	IO_L39N_Y	A17
1	IO_L39P_Y	E17
1	IO_L40N_Y	F17
1	IO_L40P_Y	C17
1	IO_L41N_YY	E18
1	IO_VREF_L41P_YY	A18
1	IO_L42N_YY	D18
1	IO_L42P_YY	A19
1	IO_L43N_Y	B19
1	IO_L43P_Y	G18
1	IO_L44N_Y	D19
1	IO_L44P_Y	H18
1	IO_L45N_YY	F18
1	IO_VREF_L45P_YY	F19 ¹
1	IO_L46N_YY	B20
1	IO_L46P_YY	K17
1	IO_L47N_Y	D20 ⁴
1	IO_L47P_Y	A20 ⁴
1	IO_L48N_Y	G19
1	IO_L48P_Y	C20
1	IO_L49N_Y	K18
1	IO_L49P_Y	E20
1	IO_L50N_YY	B21 ⁴
1	IO_L50P_YY	D21 ⁴
1	IO_L51N_YY	F20
1	IO_L51P_YY	A21

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
1	IO_L52N_YY	C21
1	IO_VREF_L52P_YY	A22
1	IO_L53N_YY	H19
1	IO_L53P_YY	B22
1	IO_L54N_YY	E21
1	IO_L54P_YY	D22
1	IO_L55N_YY	F21
1	IO_VREF_L55P_YY	C22
1	IO_L56N_YY	H20
1	IO_L56P_YY	E22
1	IO_L57N_Y	G21
1	IO_L57P_Y	A23
1	IO_L58N_Y	A24
1	IO_L58P_Y	K19
1	IO_L59N_YY	C24
1	IO_VREF_L59P_YY	B24
1	IO_L60N_YY	H21
1	IO_L60P_YY	G22
1	IO_L61N_Y	E23
1	IO_L61P_Y	C25
1	IO_L62N_Y	D24
1	IO_L62P_Y	A26
1	IO_L63N_YY	B26
1	IO_VREF_L63P_YY	K20
1	IO_L64N_YY	D25
1	IO_L64P_YY	J21
1	IO_L65N_Y	C26 ⁴
1	IO_L65P_Y	F23 ⁴
1	IO_L66N_Y	B27
1	IO_VREF_L66P_Y	G23 ¹
1	IO_L67N_Y	A27
1	IO_L67P_Y	F24
1	IO_L68N_YY	B28 ³
1	IO_L68P_YY	A28 ⁴
1	IO_WRITE_L69N_YY	K21
1	IO_CS_L69P_YY	C27

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
3	IO_L153P_YY	AD31
3	IO_VREF_L153N_YY	AF33
3	IO_L154P_Y	AC28
3	IO_L154N_Y	AF31
3	IO_L155P_Y	AC27 ⁵
3	IO_L155N_Y	AF32 ⁴
3	IO_L156P_Y	AE29
3	IO_VREF_L156N_Y	AD28 ²
3	IO_L157P_YY	AD30
3	IO_L157N_YY	AG32
3	IO_L158P_YY	AC26 ⁵
3	IO_L158N_YY	AH33 ⁴
3	IO_L159P_YY	AD26
3	IO_VREF_L159N_YY	AF30
3	IO_L160P_Y	AC25
3	IO_L160N_Y	AH32
3	IO_L161P_Y	AE28 ⁵
3	IO_L161N_Y	AL34 ⁴
3	IO_L162P_Y	AG30
3	IO_L162N_Y	AD27
3	IO_L163P_YY	AF29
3	IO_L163N_YY	AK34
3	IO_L164P_YY	AD25 ⁵
3	IO_L164N_YY	AE27 ⁴
3	IO_L165P_Y	AJ33
3	IO_VREF_L165N_Y	AH31
3	IO_L166P_Y	AE26
3	IO_L166N_Y	AL33
3	IO_L167P	AF28
3	IO_L167N	AL32
3	IO_L168P_Y	AJ31
3	IO_VREF_L168N_Y	AF27
3	IO_L169P_Y	AG29
3	IO_L169N_Y	AJ32

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
3	IO_L170P_Y	AK33
3	IO_L170N_Y	AH30
3	IO_D7_L171P_YY	AK32
3	IO_INIT_L171N_YY	AK31
3	IO	V34
4	GCK0	AH18
4	IO	AE21 ³
4	IO	AG18
4	IO	AG23
4	IO	AH24 ³
4	IO	AH25 ³
4	IO	AJ28 ³
4	IO	AK18 ³
4	IO	AK19 ³
4	IO	AL25
4	IO	AL27 ³
4	IO	AL30 ³
4	IO	AN18
4	IO	AN22 ³
4	IO	AN24 ³
4	IO_L172P_YY	AP31
4	IO_L172N_YY	AK29
4	IO_L173P_Y	AP30
4	IO_L173N_Y	AN31
4	IO_L174P_Y	AH27
4	IO_L174N_Y	AN30
4	IO_VREF_L175P_Y	AM30
4	IO_L175N_Y	AK28
4	IO_L176P_Y	AG26
4	IO_L176N_Y	AN29
4	IO_L177P_YY	AF25
4	IO_L177N_YY	AM29
4	IO_VREF_L178P_YY	AL29